

Low drop power Schottky rectifier

Main product characteristics

$I_{F(AV)}$	2 x 5 A
V_{RRM}	40 V
T_j (max)	150° C
V_F (max)	0.46 V

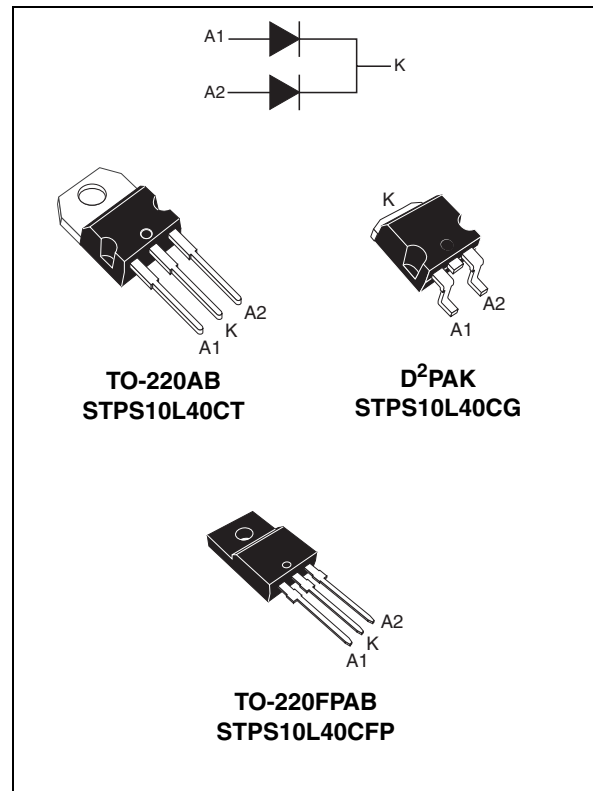
Features and Benefits

- Low forward voltage drop meaning very small conduction losses
- Low dynamic losses as a result of the schottky barrier
- Insulated package: TO-220FPAB
insulating voltage = 2000 V DC
capacitance = 12 pF
- Avalanche capability specified

Description

Dual center tap Schottky rectifiers suited for Switched Mode Power Supplies and high frequency DC to DC converters.

Packaged in TO-220AB, TO-220FPAB and D²PAK, these devices are intended for use in low voltage, high frequency inverters, free-wheeling and polarity protection applications.



1 Characteristics

Table 1. Absolute ratings (limiting values)

Symbol	Parameter				Value	Unit
V _{RRM}	Repetitive peak reverse voltage				40	V
I _{F(RMS)}	RMS forward voltage				20	A
I _{F(AV)}	Average forward current	TO-220AB D ² PAK	T _c = 135° C δ = 0.5	Per diode Per device	5 10	A
		TO-220FPAB	T _c = 140° C δ = 0.5	Per diode Per device	5 10	A
I _{FSM}	Surge non repetitive forward current		t _p = 10 ms sinusoidal		150	A
I _{RRM}	Repetitive peak reverse current		t _p = 2 μs square F = 1 kHz		1	A
I _{RSM}	Non repetitive peak reverse current		t _p = 100 μs square		2	A
P _{ARM}	Repetitive peak avalanche power		t _p = 1 μs T _j = 25°C		2700	W
T _{stg}	Storage temperature range				-65 to + 150	° C
T _j	Maximum operating junction temperature ⁽¹⁾				150	° C
dV/dt	Critical rate of rise of reverse voltage				10000	V/μs

1. $\frac{dP_{tot}}{dT_j} < \frac{1}{R_{th(j-a)}}$ condition to avoid thermal runaway for a diode on its own heatsink

Table 2. Thermal resistances

Symbol	Parameter			Value	Unit
R _{th(j-c)}	Junction to case	TO-220AB / D ² PAK	Per diode Total	3 1.7	°C/W
R _{th(c)}			Coupling	0.35	
R _{th(j-c)}	Junction to case	TO-220FPAB	Per diode Total	5 3.8	°C/W
R _{th(c)}			Coupling	2.5	

When the diodes 1 and 2 are used simultaneously :

$$\Delta T_j(\text{diode 1}) = P(\text{diode1}) \times R_{th(j-c)}(\text{Per diode}) + P(\text{diode 2}) \times R_{th(c)}$$

Table 3. Static electrical characteristics (per diode)

Symbol	Parameter	Test Conditions		Min.	Typ.	Max.	Unit
I _R ⁽¹⁾	Reverse leakage current	T _j = 25° C	V _R = V _{RRM}			0.2	mA
		T _j = 100° C			8	25	mA
V _F ⁽¹⁾	Forward voltage drop	T _j = 25° C	I _F = 5 A			0.53	V
		T _j = 100° C	I _F = 5 A		0.36	0.46	
		T _j = 25° C	I _F = 10 A			0.67	
		T _j = 125° C	I _F = 10 A		0.49	0.59	

1. Pulse test: t_p = 380 μs, δ < 2%

To evaluate the conduction losses use the following equation:

$$P = 0.33 \times I_{F(AV)} + 0.026 I_{F(RMS)}^2$$

Figure 1. Average forward power dissipation versus average forward current (per diode)

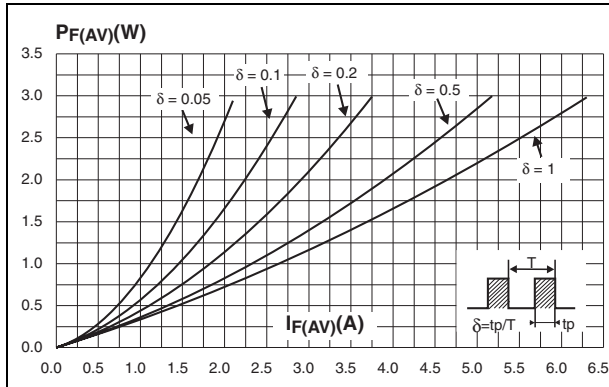


Figure 2. Average forward current versus ambient temperature (delta = 0.5, per diode)

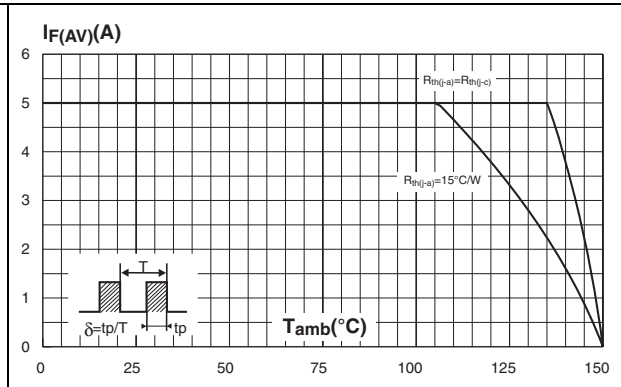


Figure 3. Normalized avalanche power derating versus pulse duration

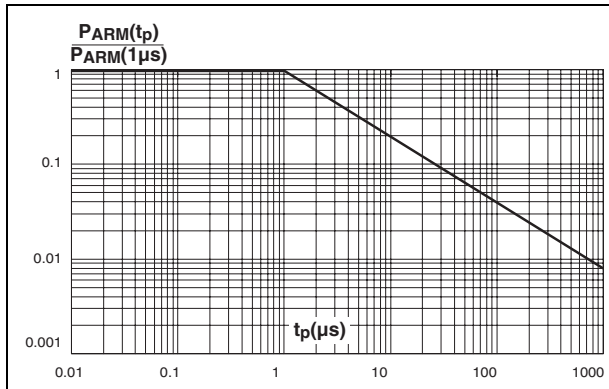


Figure 4. Normalized avalanche power derating versus junction temperature

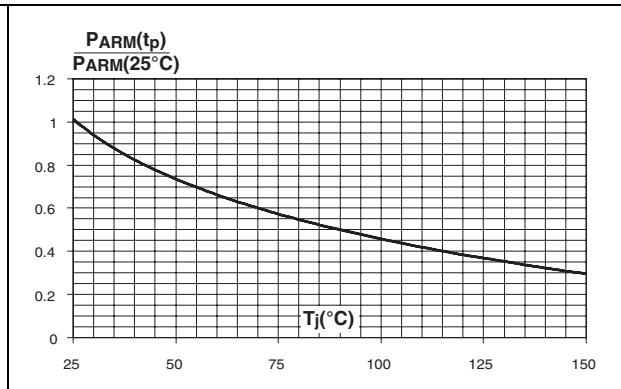


Figure 5. Non repetitive surge peak forward current versus overload duration (maximum values, per diode) (TO-220AB and D²PAK).

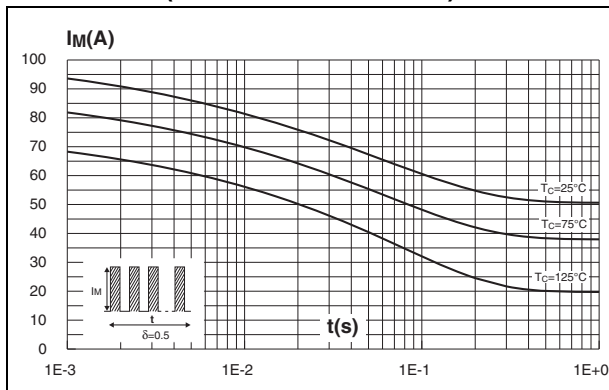


Figure 6. Non repetitive surge peak forward current versus overload duration (maximum values, per diode) (TO-220FPAB)

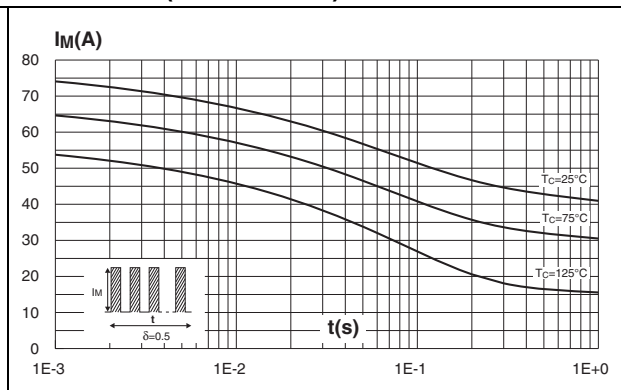


Figure 7. Relative variation of thermal impedance junction to case versus pulse duration (TO-220AB and D²PAK)

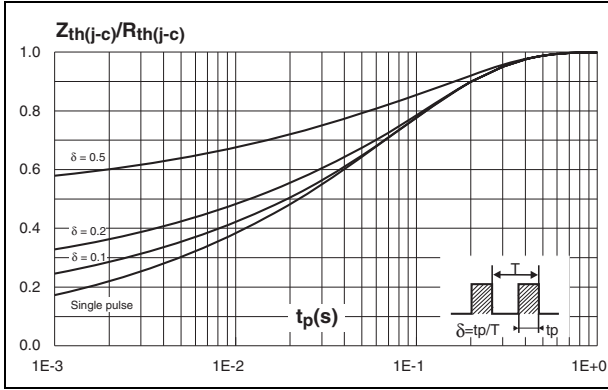


Figure 8. Relative variation of thermal impedance junction to case versus pulse duration (TO-220FPAB)

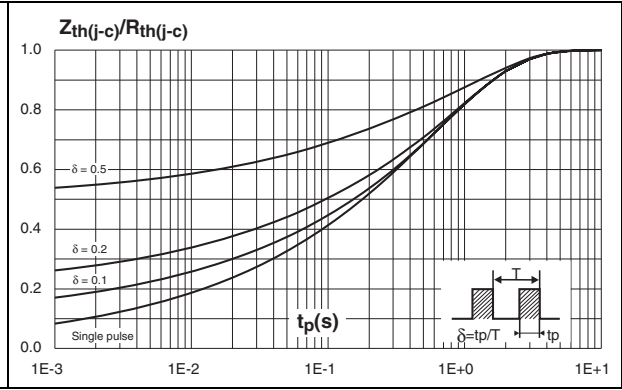


Figure 9. Reverse leakage current versus reverse voltage applied (typical values, per diode)

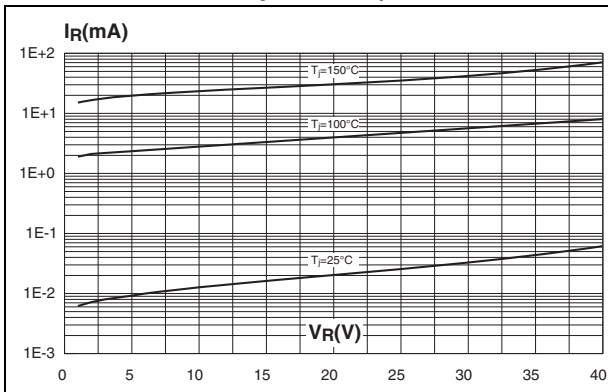


Figure 10. Junction capacitance versus reverse voltage applied (typical values, per diode)

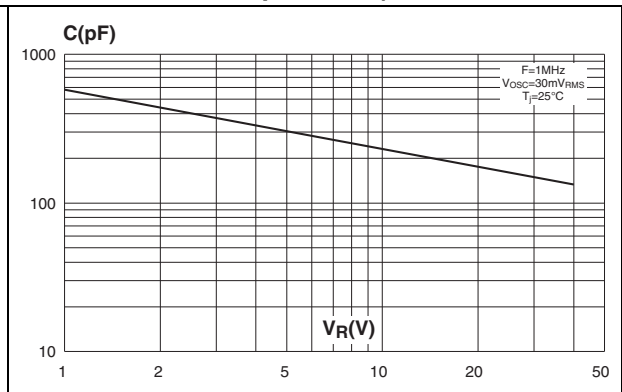


Figure 11. Forward voltage drop versus forward current (maximum values, per diode)

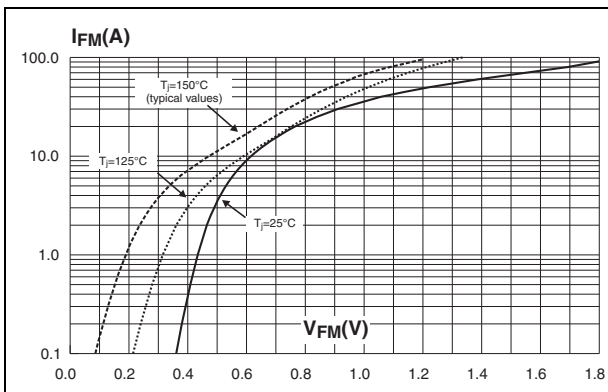
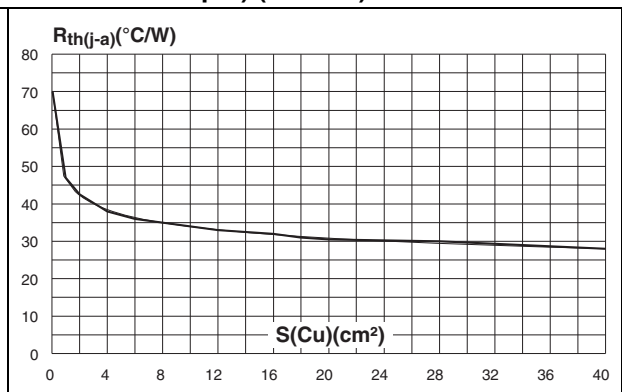


Figure 12. Thermal resistance junction to ambient versus copper surface under tab (Epoxy printed circuit board FR4, copper thickness: 35 μm) (D²PAK)



2 Package Information

- Epoxy meets UL94, V0
- Cooling method: by conduction (C)
- Recommended torque value: 0.55 Nm
- Maximum torque value: 0.70 Nm

Table 4. TO-220AB dimensions

Ref	Dimensions			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	4.40	4.60	0.173	0.181
C	1.23	1.32	0.048	0.051
D	2.40	2.72	0.094	0.107
E	0.49	0.70	0.019	0.027
F	0.61	0.88	0.024	0.034
F1	1.14	1.70	0.044	0.066
F2	1.14	1.70	0.044	0.066
G	4.95	5.15	0.194	0.202
G1	2.40	2.70	0.094	0.106
H2	10	10.40	0.393	0.409
L2	16.4 typ.		0.645 typ.	
L4	13	14	0.511	0.551
L5	2.65	2.95	0.104	0.116
L6	15.25	15.75	0.600	0.620
L7	6.20	6.60	0.244	0.259
L9	3.50	3.93	0.137	0.154
M	2.6 typ.		0.102 typ.	
Diam.	3.75	3.85	0.147	0.151

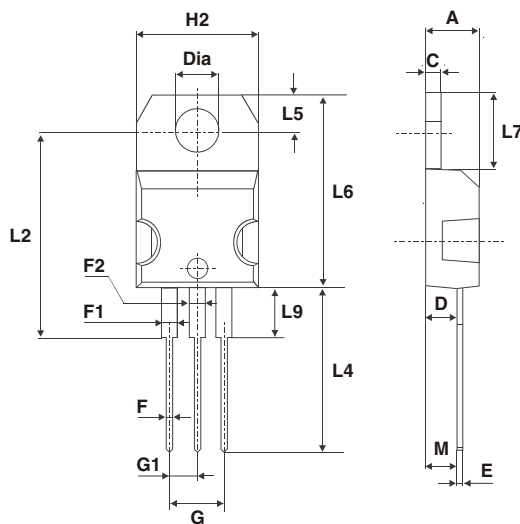


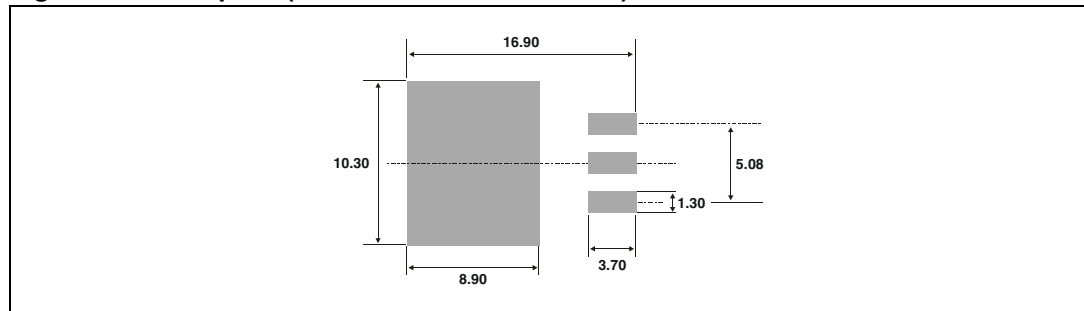
Table 5. TO-220FPAB dimensions

Ref	Dimensions			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	4.4	4.9	0.173	0.193
B	2.5	2.9	0.098	0.114
D	2.45	2.75	0.098	0.114
E	0.4	0.70	0.016	0.027
F	0.60	1	0.024	0.039
F1	1.15	1.70	0.045	0.067
F2	1.15	1.70	0.045	0.067
G	4.95	5.20	0.195	0.204
G1	2.40	2.70	0.094	0.106
H	10	10.7	0.393	0.421
L2	16 Typ.		0.63 Typ.	
L3	28.6	30.6	1.126	1.204
L4	9.8	10.7	0.385	0.421
L6	15.8	16.4	0.621	0.645
L7	9.00	9.90	0.354	0.389
Dia.	2.9	3.50	0.114	0.18

Table 6. D²PAK dimensions

Ref	Dimensions			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	4.40	4.60	0.173	0.181
A1	2.49	2.69	0.098	0.106
A2	0.03	0.23	0.001	0.009
B	0.70	0.93	0.027	0.037
B2	1.14	1.70	0.045	0.067
C	0.45	0.60	0.017	0.024
C2	1.23	1.36	0.048	0.054
D	8.95	9.35	0.352	0.368
E	10.00	10.40	0.393	0.409
G	4.88	5.28	0.192	0.208
L	15.00	15.85	0.590	0.624
L2	1.27	1.40	0.050	0.055
L3	1.40	1.75	0.055	0.069
M	2.40	3.20	0.094	0.126
R	0.40 typ.		0.016 typ.	
V2	0°	8°	0°	8°

Figure 13. Footprint (dimensions in millimeters)



In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com.

3 Ordering information

Ordering type	Marking	Package	Weight	Base qty	Delivery mode
STPS10L40CT	STPS10L40CT	TO-220AB	2.23 g	50	Tube
STPS10L40CFP	STPS10L40CFP	TO-200FPAB	2 g	50	Tube
STPS10L40CG	STPS10L40CG	D ² PAK	1.48 g	50	Tube
STPS10L40CG-TR	STPS10L40CG	D ² PAK	1.48 g	1000	Tape and reel

4 Revision history

Date	Revision	Description of Changes
Jul-2003	5B	Last release.
23-Mar-2007	6	Removed ISOWATT package.

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